

	Docket Number (Optional) FUJI:141A		Application Number 10/646,586
	Applicant(s) Katsunori UENO		
	Filing Date August 22, 2003	Group Art Unit 2811	

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
<i>[Signature]</i>	US	5,776,837	7/98	Palmour	438	767	
<i>[Signature]</i>	US	5,506,421	4/96	Palmour	257	77	
<i>[Signature]</i>	US	6,002,143	12/99	Terasawa	257	77	

FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

<i>[Signature]</i>	"Vital Issues for SiC Power Devices"; K. Hara; Materials Science Forum Vols. 264-268 (1998); pgs. 901-906; 1998 Trans Tech Publications, Switzerland
<i>[Signature]</i>	"High Voltage Planar 6H-SiC Accufet"; P.M. Shenoy et al.; Materials Science Forum Vols. 264-268 (1998); pgs. 993-996; 1998 Trans Tech Publications, Switzerland

EXAMINER <i>[Signature]</i>	DATE CONSIDERED 4/2/04
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.